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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary) of

Complete if Known					
Application Number	09/845,945				
Filing Date	Apr 30, 2001				
First Named Inventor	Poh Boon Phua				
Group Art Unit	<del>-2874</del> 2828				
Examiner Name					
Attorney Docket Number	1085-022-PWH				

		OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s).			
CHI	/	US Patent Application No. 09/963,181 "An Apparatus for Generating Laser Radiation" filed 9/25/01; 18 pages			
		BOWMAN et al; "High Power Diode Pumped Micron Lasers" SPIE Vol. 1865 pp 156 - 163; 1993	_		
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Examiner Signature Date Considered 9/25/02						7	
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